DSC4001

Silicon NPN epitaxial planar type

For general amplification
Complementary to DSA4001
DSC2001 in NS through hole type package

■ Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- \bullet Low collector-emitter saturation voltage $V_{\text{CE}(\text{sat})}$
- Contributes to miniaturization of sets, mount area reduction
- Eco-friendly Halogen-free package

■ Packaging

Radial type: 5000 pcs / carton

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	60	V
Collector-emitter voltage (Base open)	V_{CEO}	50	V
Emitter-base voltage (Collector open)	$V_{\rm EBO}$	7	V
Collector current	I_{C}	100	mA
Peak collector current	I _{CP}	200	mA
Collector power dissipation	P _C	300	mW
Junction temperature	T_{j}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

■ Package

- Code
 - NS-B2-B-B
- Pin Name
 - 1. Emitter
 - 2. Collector
 - 3. Base
- Marking Symbol: C1

■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \mu A, I_E = 0$	60			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_E = 10 \mu A, I_C = 0$	7			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_{E} = 0$			0.1	μΑ
Collector-emitter voltage (Base open)	I _{CEO}	$V_{CE} = 10 \text{ V}, I_{B} = 0$			100	
Forward current transfer ratio *	h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$	210		460	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$		0.13	0.3	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		1.5		pF

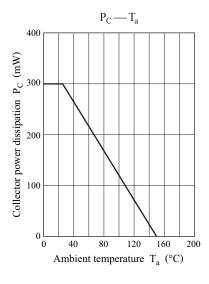
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

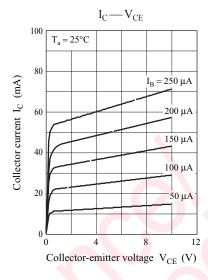
2. *: Rank classification

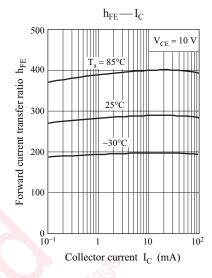
Code	R	S	0	
Rank	R	S	No-rank	
h_{FE}	210 to 340	290 to 460	210 to 460	
Marking Symbol	C1R	C1S	C1	

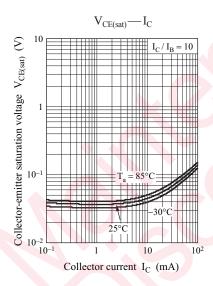
Product of no-rank is not classified and have no marking symbol for rank.

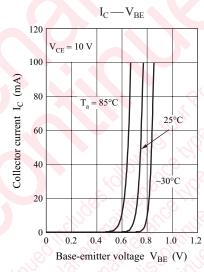
DSC4001 Panasonic

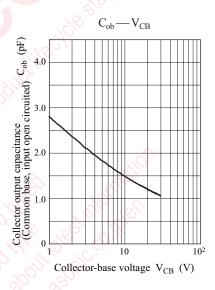


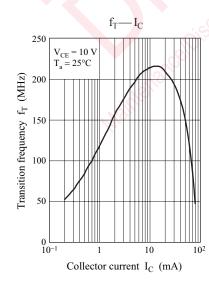








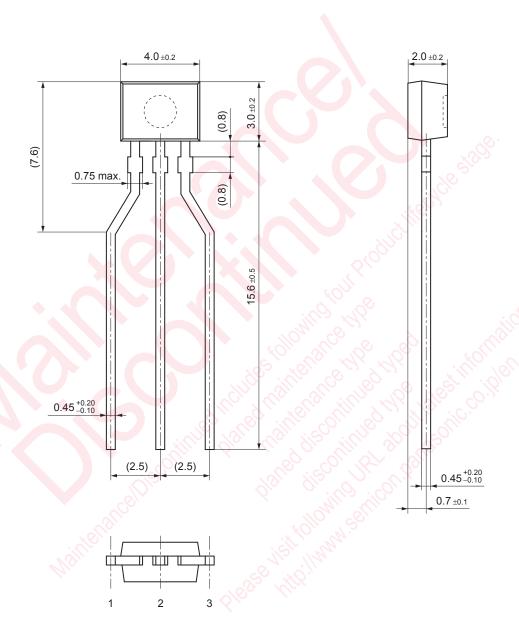




2 Ver. AED

Panasonic DSC4001

NS-B2-B-B Unit: mm



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